8-bit parallel-in/serial out shift register Rev. 1 — 25 September 2013

Product data sheet

1. General description

The 74HC166-Q100; 74HCT166-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and a serial output (Q7). When the parallel enable input (\overline{PE}) is LOW, the data from D0 to D7 is loaded into the shift register on the next LOW-to-HIGH transition of the clock input (CP). When \overline{PE} is HIGH, data enters the register serially at DS with each LOW-to-HIGH transition of CP. When the clock enable input (\overline{CE}) is LOW data is shifted on the LOW-to-HIGH transitions of CP. A HIGH on \overline{CE} disables the CP input. Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC166-Q100: CMOS level
 - ◆ For 74HCT166-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

3. Ordering information

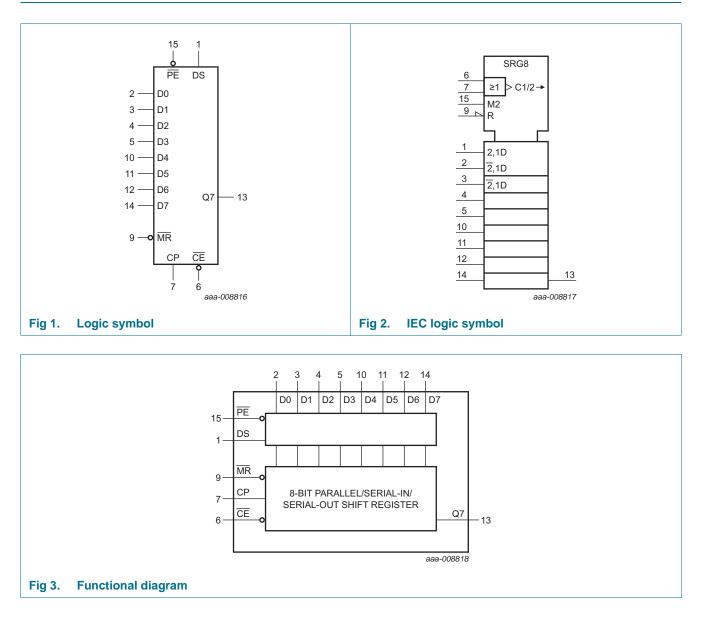
Table 1. Ordering information

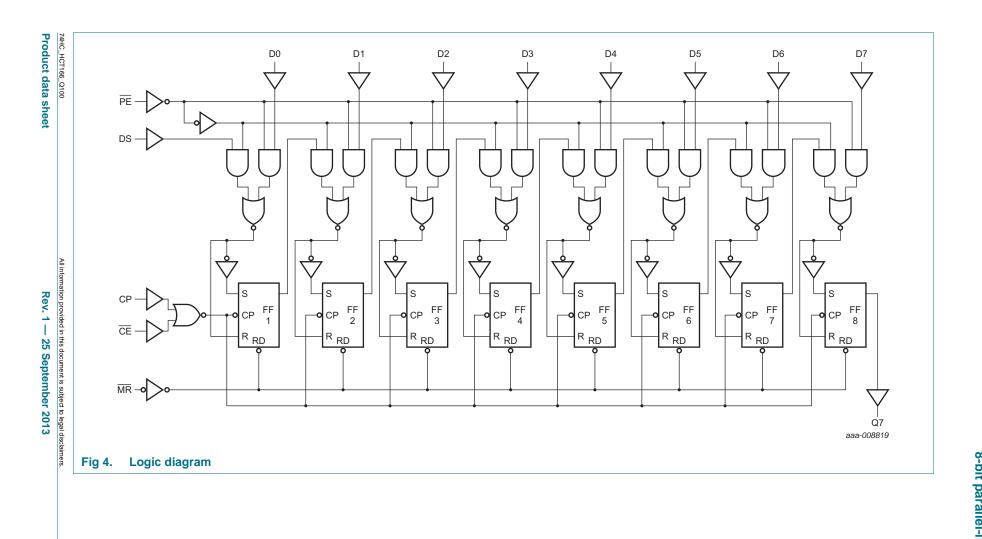
Type number	Package								
	Temperature range	Name	Description	Version					
74HC166D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body	SOT109-1					
74HCT166D-Q100			width 3.9 mm						
74HC166PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					



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4. Functional diagram





74HC166-Q100; 74HCT166-Q100 8-bit parallel-in/serial out shift register

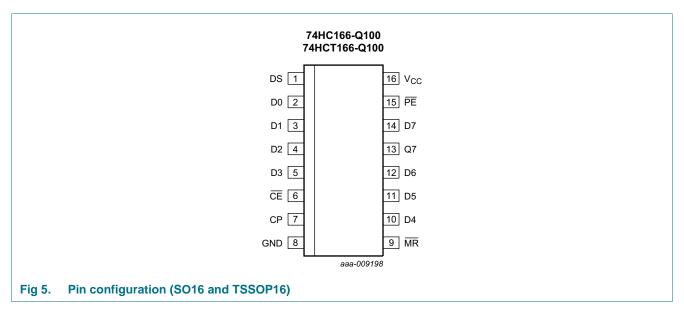
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5. Pinning information

5.1 Pinning



5.2 Pin description

. . . .

Table 2.	Pin description	
Symbol	Pin	Description
DS	1	serial data input
D0 to D7	2, 3, 4, 5, 10, 11, 12, 14	parallel data inputs
CE	6	clock enable input (active LOW)
СР	7	clock input (LOW-to-HIGH edge-triggered)
GND	8	ground (0 V)
MR	9	asynchronous master reset (active LOW)
Q7	13	serial output from the last stage
PE	15	parallel enable input (active LOW)
V _{CC}	16	positive supply voltage

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6. Functional description

Table 3.Function table^[1]

Operating modes	Inputs			Qn regi	Output			
	PE	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7
parallel load	I	I	1	Х	I	L	L to L	L
	Ι	I	\uparrow	Х	h	Н	H to H	Н
serial shift	h	I	\uparrow	I	Х	L	q0 to q5	q6
	h	I	\uparrow	h	Х	Н	q0 to q5	q6
hold "do nothing"	Х	Н	Х	Х	Х	q0	q1 to q6	q7

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

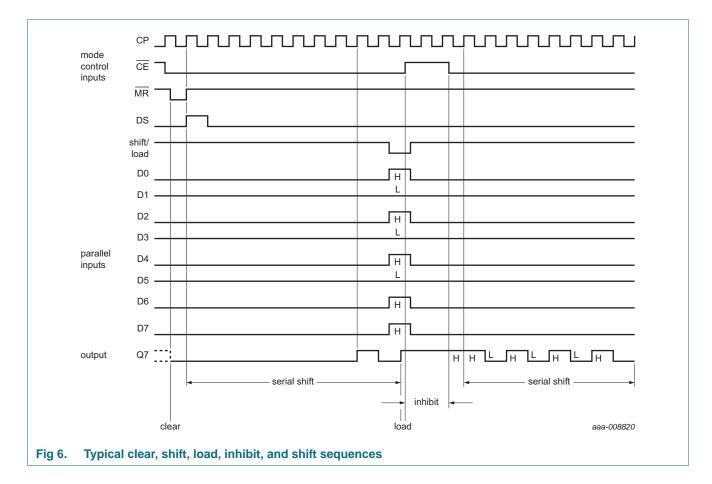
L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 \uparrow = LOW-to-HIGH clock transition.



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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> -	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}}$ + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C			
		SO16 package	[2] _	500	mW
		TSSOP16 package	[3]	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC1	66-Q100	1	74HCT166-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C	to +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6-Q100							1		
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{ОН}	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = -20 μ A; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I_{O} = 5.2 mA; V_{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
1	input leakage current	$V_I = V_{CC} \text{ or GND};$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μA
lcc	supply current		-	-	8.0	-	80	-	160	μA

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	66-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
VIL	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{ОН}	HIGH-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 5.2 mA; V_{CC} = 4.5 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 4.5 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current		-	-	8.0	-	80	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_1 = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP and \overline{CE} inputs	-	80	288	-	360	-	392	μΑ
		MR input	-	40	144	-	180	-	196	μΑ
		PE input	-	60	216	-	270	-	294	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

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10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); $t_r = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbol	Parameter	Conditions		25 °C	;	−40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6-Q100									
t _{pd}	propagation	CP to Q7; see Figure 7	[1]							
	delay	$V_{CC} = 2.0 V$	-	50	150	-	190	-	225	ns
		$V_{CC} = 4.5 V$	-	18	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$	-	14	26	-	33	-	38	ns
		MR to Q7; see Figure 8								
		$V_{CC} = 2.0 V$	-	47	160	-	200	-	240	ns
		$V_{CC} = 4.5 V$	-	17	32	-	40	-	48	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	14	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$	-	14	27	-	34	-	41	ns
t _t	transition	output; see Figure 7	[2]							
	time	$V_{CC} = 2.0 V$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$	-	6	13	-	16	-	19	ns
t _w pulse width	pulse width	CP input HIGH or LOW; see Figure 7								
		$V_{CC} = 2.0 V$	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$	14	5	-	17	-	20	-	ns
		MR input LOW; see Figure 8								
		$V_{CC} = 2.0 V$	100	25	-	125	-	150	-	ns
		$V_{CC} = 4.5 V$	20	9	-	25	-	30	-	ns
		$V_{CC} = 6.0 V$	17	7	-	21	-	26	-	ns
t _{rec}	recovery time	MR to CP; see Figure 8								
		$V_{CC} = 2.0 V$	0	-19	-	0	-	0	-	ns
		$V_{CC} = 4.5 V$	0	-7	-	0	-	0	-	ns
		$V_{CC} = 6.0 V$	0	-6	-	0	-	0	-	ns
t _{su}	set-up time	Dn, CE to CP; see Figure 9								
		$V_{CC} = 2.0 V$	80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 V$	16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$	14	4	-	17	-	20	-	ns
		PE to CP; see Figure 9								
		V _{CC} = 2.0 V	100	33	-	125	-	150	-	ns
		$V_{CC} = 4.5 V$	20	12	-	25	-	30	-	ns
		$V_{CC} = 6.0 V$	17	10	-	21	-	26	-	ns

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	Conditions		25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	-
hold time	Dn, CE to CP; see Figure 9									
			2	-8	-	2	-	2	-	ns
			2	-3	-	2	-	2	-	ns
			2	-2	-	2	-	2	-	ns
	PE to CP; see Figure 9									
	$V_{CC} = 2.0 V$		0	-28	-	0	-	0	-	ns
			0	-10	-	0	-	0	-	ns
	$V_{\rm CC} = 6.0 \rm V$		0	-8	-	0	-	0	-	ns
maximum	CP input; see Figure 7									
frequency	$V_{CC} = 2.0 V$		6	19	-	4.8	-	4	-	MH
	$V_{CC} = 4.5 V$		30	57	-	24	-	20	-	MH
	$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	63	-	-	-	-	-	MH
	$V_{\rm CC} = 6.0 \text{V}$		35	68	-	28	-	24	-	MH
power dissipation capacitance		<u>[3]</u>	-	41	-	-	-	-	-	pF
6-Q100										
propagation	CP to Q7; see Figure 7	[1]								
delay	$V_{CC} = 4.5 V$		-	23	40	-	50	-	60	ns
	V _{CC} = 5.0 V; C _L = 15 pF		-	20	-	-	-	-	-	ns
	MR to Q7; see Figure 8									
	V _{CC} = 4.5 V		-	22	40	-	50	-	60	ns
	V _{CC} = 5.0 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
transition	output; see Figure 7	[2]								
time	V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
pulse width	CP input HIGH or LOW; see <u>Figure 7</u>									
	$V_{CC} = 4.5 V$		20	9	-	25	-	30	-	ns
	MR input LOW; see Figure 8									
	$V_{CC} = 4.5 V$		25	11	-	31	-	38	-	ns
recovery time	MR to CP; see Figure 8									
	$V_{CC} = 4.5 V$		0	-7	-	0	-	0	-	ns
set-up time	Dn, CE to CP; see Figure 9									
	V _{CC} = 4.5 V		16	8	-	20	-	24	-	ns
	PE to CP; see Figure 9									
	V _{CC} = 4.5 V		30	15	-	38	-	45	-	ns
hold time	Dn, CE to CP; see Figure 9									
	V _{CC} = 4.5 V		0	-3	-	0	-	0	-	ns
	PE to CP; see Figure 9									
	maximum frequency power dissipation capacitance propagation delay transition time pulse width pulse width recovery time set-up time	Vcc = 2.0 VVcc = 4.5 VVcc = 6.0 VPE to CP; see Figure 9Vcc = 2.0 VVcc = 4.5 VVcc = 4.5 VVcc = 6.0 Vmaximum frequencyCP input; see Figure 7Vcc = 2.0 VVcc = 4.5 VVcc = 5.0 V; CL = 15 pFVcc = 6.0 VPower dissipation capacitancepropagation delayCP to Q7; see Figure 7Vcc = 4.5 VVcc = 4.5 VVcc = 5.0 V; CL = 15 pFVcc = 4.5 VVcc = 4.5 VPulse widthCP input HIGH or LOW; see Figure 7Vcc = 4.5 VPulse widthPulse widthCP input HIGH or LOW; see Figure 7Vcc = 4.5 VPulse widthPulse	$\begin{tabular}{ c c c c } \hline V_{CC} = 2.0 V \\ \hline V_{CC} = 4.5 V \\ \hline V_{CC} = 6.0 V \\\hline \hline PE to CP; see Figure 9 \\ \hline V_{CC} = 2.0 V \\ \hline V_{CC} = 4.5 V \\ \hline V_{CC} = 6.0 V \\\hline \hline V_{CC} = 6.0 V \\\hline \hline V_{CC} = 2.0 V \\\hline V_{CC} = 2.0 V \\\hline V_{CC} = 2.0 V \\\hline V_{CC} = 4.5 V \\\hline V_{CC} = 5.0 V; C_L = 15 pF \\\hline V_{CC} = 6.0 V \\\hline \hline V_{CC} = 5.0 V; C_L = 15 pF \\\hline \hline V_{CC} = 4.5 V \\\hline V_{CC} = 5.0 V; C_L = 15 pF \\\hline \hline \hline MR to Q7; see Figure 7 \\\hline \hline V_{CC} = 5.0 V; C_L = 15 pF \\\hline \hline \hline MR to Q7; see Figure 8 \\\hline V_{CC} = 4.5 V \\\hline V_{CC} = 4.5 V \\\hline V_{CC} = 4.5 V \\\hline \hline V_{CC} = 4.5 V \\\hline \hline V_{CC} = 4.5 V \\\hline \hline Rime \\\hline \hline MR input LOW; see Figure 8 \\\hline V_{CC} = 4.5 V \\\hline \hline RR to CP; see Figure 8 \\\hline V_{CC} = 4.5 V \\\hline \hline MR input LOW; see Figure 8 \\\hline V_{CC} = 4.5 V \\\hline \hline MR to CP; see Figure 8 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline \hline \hline \hline \hline \hline \hline PE to CP; see Figure 9 \\\hline V_{CC} = 4.5 V \\\hline \hline $	hold time Dn, CE to CP; see Figure 9 2 $V_{CC} = 2.0 V$ 2 $V_{CC} = 6.0 V$ 2 $V_{CC} = 6.0 V$ 2 \overline{PE} to CP; see Figure 9 0 $V_{CC} = 2.0 V$ 0 $V_{CC} = 4.5 V$ 0 $V_{CC} = 6.0 V$ 0 $V_{CC} = 2.0 V$ 6 $V_{CC} = 2.0 V$ 6 $V_{CC} = 6.0 V$ 30 $V_{CC} = 6.0 V$ 35 power per package; [3] $V_{I} = GND to V_{CC}$ 10 see-Q100 V_{CC} = 4.5 V - propagation CP to Q7; see Figure 7 [1] $V_{CC} = 4.5 V$ - - $V_{CC} = 5.0 V; C_L = 15 pF$ - - Ifme to Q7; see Figure 8 $V_{CC} = 4.5 V$ - $V_{CC} = 4.5 V$ 20 - Ifme input LIGH or LOW; see Figure 8	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	hold time hold time $V_{CC} = 2.0$ V 2 -8 - 2 - $V_{CC} = 2.0$ V 2 -3 - 2 - $V_{CC} = 4.5$ V 2 -3 - 2 - $V_{CC} = 6.0$ V 2 -2 - 2 - $V_{CC} = 6.0$ V 0 -28 - 0 - $V_{CC} = 4.5$ V 0 -10 - 0 - $V_{CC} = 6.0$ V 0 -8 - 0 - $V_{CC} = 2.0$ V 6 19 - 4.8 - $V_{CC} = 2.0$ V 6 19 - 4.8 - $V_{CC} = 2.0$ V 6 19 - 4.8 - $V_{CC} = 6.0$ V 30 57 - 24 - $V_{CC} = 6.0$ V 35 68 - 28 - folisispation clasispation clasispation clasispation CP to Q7; see Figure 7 10 - - -		hold time Dn, CE to CP; see Figure 9 Vcc = 2.0 V 2 -8 - 2 - 2 - Vcc = 4.5 V 2 -3 - 2 - 2 - Vcc = 6.0 V 2 -3 - 2 - 2 - Vcc = 6.0 V 0 -28 - 0 - 0 - PC = 0.0 V 0 -8 0 - 0 - 0 - Vcc = 6.0 V 0 -8 0 - 0 - 0 - Vcc = 5.0 V; CL = 15 pF - 63 - 28 - 24 - - power visispation visispation visispation - - - - - vic = 6.0 V; CL = 15 pF - 63 - 28 - 24 - - propagation per package; 12 - 41 - -

Dynamic characteristics ... continued Table 7.

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Symbol	Parameter	Conditions	25 °C			–40 °C t	o +85 °C	–40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
f _{max}	maximum	CP input; see Figure 7									
	frequency	$V_{CC} = 4.5 V$		25	45	-	20	-	17	-	MHz
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	50	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; $V_1 = GND$ to V_{CC}	<u>[3]</u>	-	41	-	-	-	-	-	pF

Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); $t_r = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

11. Waveforms

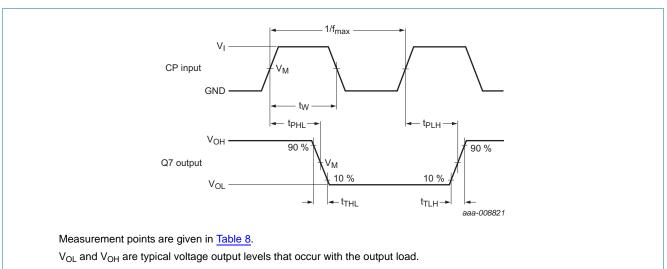
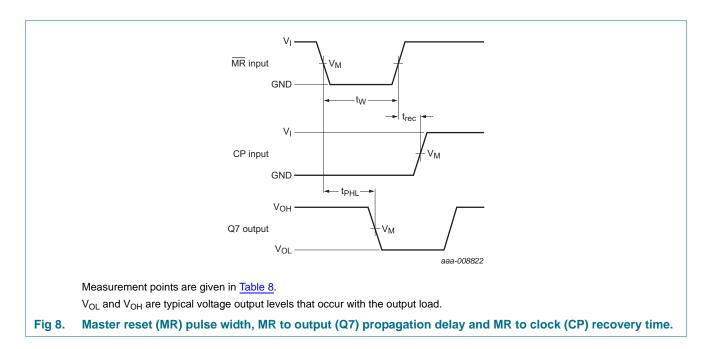
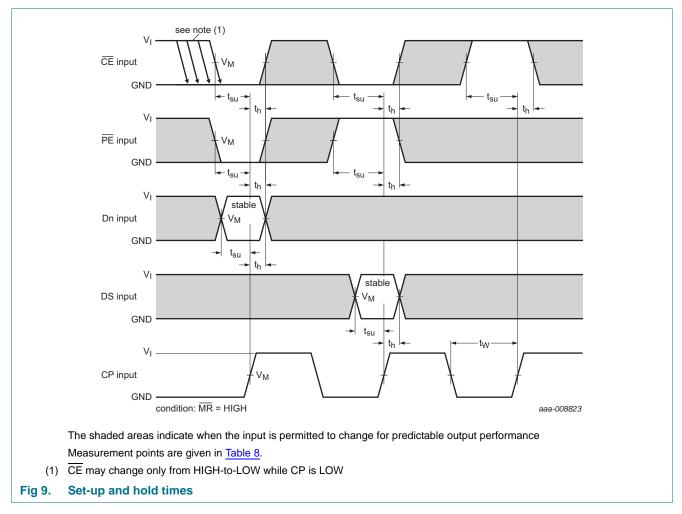


Fig 7. Clock (CP) to output (Q7) propagation delays, pulse width, output transition times and maximum frequency

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Table 8. Measurement points										
Туре	Input	Output								
	VI	V _M	V _M							
74HC166-Q100	V _{CC}	0.5V _{CC}	0.5V _{CC}							
74HCT166-Q100	3 V	1.3 V	1.3 V							

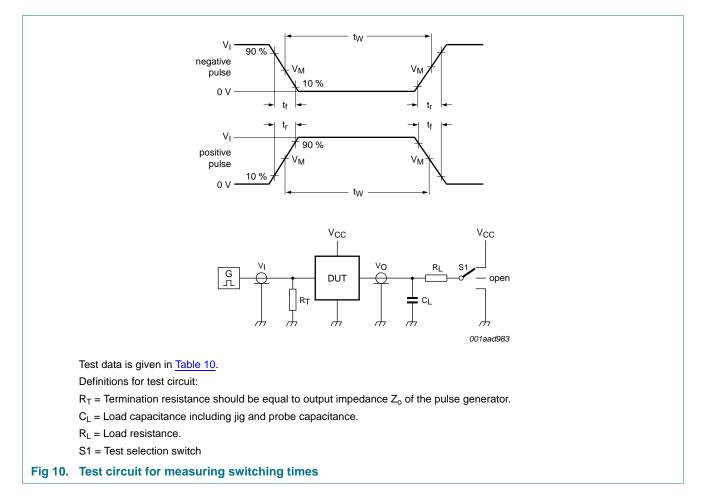


Table 9. Test data

Туре	Input		Load	Load				
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}			
74HC166-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open			
74HCT166-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open			

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12. Package outline

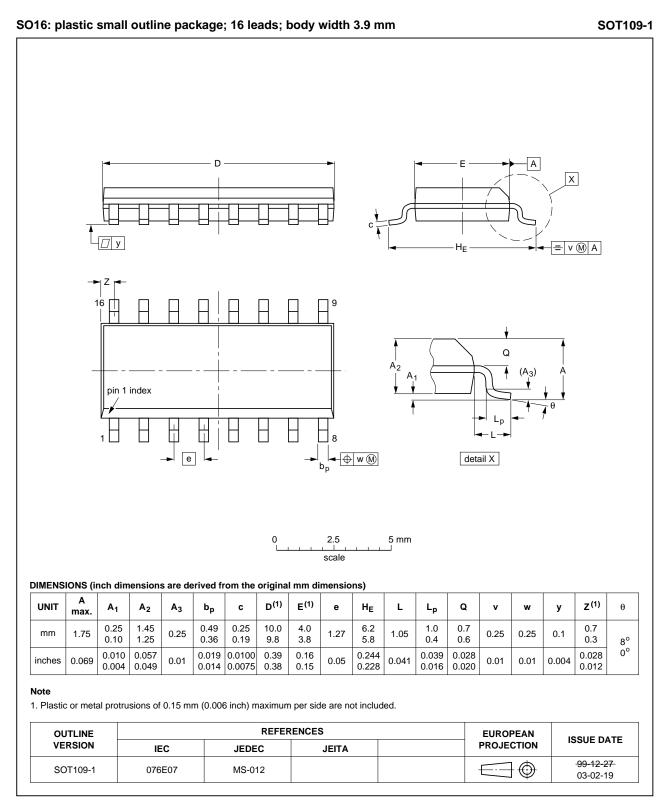


Fig 11. Package outline SOT109-1 (SO16)

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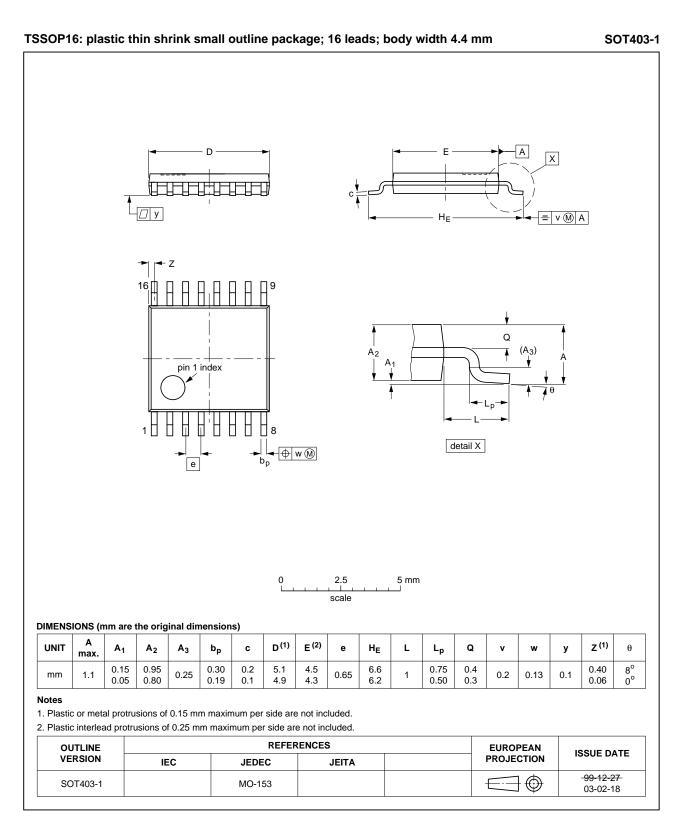


Fig 12. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

14. Revision history

Table 11. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT166_Q100 v.1	20130925	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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